# 5 V ECL 2-Input Differential AND/NAND

# MC10EL05, MC100EL05

### Description

The MC10EL/100EL05 is a 2-input differential AND/NAND gate. The device is functionally equivalent to the E404 device with higher performance capabilities. With propagation delays and output transition times significantly faster than the E404, the EL05 is ideally suited for those applications which require the ultimate in AC performance.

Because a negative 2-input NAND is equivalent to a 2-input OR function, the differential inputs and outputs of the device allows the EL05 to also be used as a 2-input differential OR/NOR gate.

The differential inputs employ clamp circuitry so that under open input conditions (pulled down to  $V_{EE}$ ) the input to the AND gate will be HIGH. In this way, if one set of inputs is open, the gate will remain active to the other input.

The 100 Series contains temperature compensation.

### Features

- 275 ps Propagation Delay
- ESD Protection:
  - > 1 kV Human Body Model,
  - ◆ > 100 V Machine Model
- PECL Mode Operating Range:
  - $V_{CC} = 4.2 \text{ V to } 5.7 \text{ V with } V_{EE} = 0 \text{ V}$
- NECL Mode Operating Range:
  - $V_{CC} = 0$  V with  $V_{EE} = -4.2$  V to -5.7 V
- Internal Input Pulldown Resistors
- Meets or Exceeds JEDEC Spec EIA/JESD78 IC Latchup Test
- Moisture Sensitivity
  - ◆ For Additional Information, see Application Note <u>AND8003/D</u>
- Flammability Rating:
  - UL 94 V-0 @ 0.125 in, Oxygen Index: 28 to 34
- Transistor Count = 44 devices
- These Devices are Pb-Free, Halogen Free and are RoHS Compliant

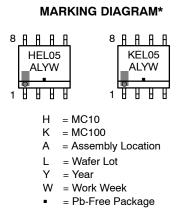


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SOIC-8 D SUFFIX CASE 751-07



(Note: Microdot may be in either location)

\*For additional marking information, refer to Application Note <u>AND8002/D</u>.

### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MC10EL05DR2G	SOIC-8 (Pb-Free)	2500 / Tape & Reel
MC100EL05DG	SOIC-8 (Pb-Free)	98 Units / Tube

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, <u>BRD8011/D</u>.

### Table 1. TRUTH TABLE

D0	D1	D0	D1	Q	Q
L	L	Н	Н	L	Н
L	Н	Н	L	L	Н
Н	L	L	Н	L	Н
Н	Н	L	L	Н	L

### **Table 2. PIN DESCRIPTION**

PIN	Function
D0, <u>D0</u> ; D1, <u>D1</u>	ECL Data Inputs
Q, <u>Q</u>	ECL Data Outputs
V <sub>CC</sub>	Positive Supply
V <sub>EE</sub>	Negative Supply

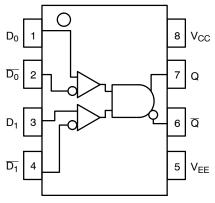


Figure 1. Logic Diagram and Pinout Assignment

### **Table 3. MAXIMUM RATINGS**

Symbol	Parameter	Condition 1	Condition 2	Rating	Unit
V <sub>CC</sub>	PECL Mode Power Supply	V <sub>EE</sub> = 0 V		8	V
V <sub>EE</sub>	NECL Mode Power Supply	V <sub>CC</sub> = 0 V		-8	V
VI	PECL Mode Input Voltage NECL Mode Input Voltage	V <sub>EE</sub> = 0 V V <sub>CC</sub> = 0 V	$\begin{array}{l} V_{I} \leq V_{CC} \\ V_{I} \geq V_{EE} \end{array}$	6 -6	V
l <sub>out</sub>	Output Current	Continuous Surge		50 100	mA
T <sub>A</sub>	Operating Temperature Range			-40 to +85	°C
T <sub>stg</sub>	Storage Temperature Range			-65 to +150	°C
θ <sub>JA</sub>	Thermal Resistance (Junction-to-Ambient)	0 lfpm 500 lfpm	SOIC-8	190 130	°C/W
θJC	Thermal Resistance (Junction-to-Case)	Standard Board	SOIC-8	41 to 44	°C/W
T <sub>sol</sub>	Wave Solder (Pb-Free)	<2 to 3 sec @ 260°C		265	°C

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm.

Input and output parameters vary 1:1 with V<sub>CC</sub>. V<sub>EE</sub> can vary +0.25 V / -0.5 V.
Outputs are terminated through a 50 Ω resistor to V<sub>CC</sub> - 2.0 V.
V<sub>IHCMR</sub> min varies 1:1 with V<sub>EE</sub>, V<sub>IHCMR</sub> max varies 1:1 with V<sub>CC</sub>. The V<sub>IHCMR</sub> range is referenced to the most positive side of the differential input signal. Normal operation is obtained if the HIGH level falls within the specified range and the peak-to-peak voltage lies between V<sub>PP(min)</sub> and 1.0 V.

# MC10EL05, MC100EL05

		-40°C				25°C			85°C			
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit	
I <sub>EE</sub>	Power Supply Current		18	22		18	22		18	22	mA	
V <sub>OH</sub>	Output HIGH Voltage (Note 2)	3920	4010	4110	4020	4105	4190	4090	4185	4280	mV	
V <sub>OL</sub>	Output LOW Voltage (Note 5)	3050	3200	3350	3050	3210	3370	3050	3227	3405	mV	
V <sub>IH</sub>	Input HIGH Voltage (Single-Ended)	3770		4110	3870		4190	3940		4280	mV	
V <sub>IL</sub>	Input LOW Voltage (Single-Ended)	3050		3500	3050		3520	3050		3555	mV	
VIHCMR	Input HIGH Voltage Common Mode Range (Differential Configuration) (Note 6)	3.0		4.6	3.0		4.6	3.0		4.6	V	
I <sub>IH</sub>	Input HIGH Current			150			150			150	μA	
Ι <sub>ΙL</sub>	Input LOW Current	0.5			0.5			0.3			μA	

### Table 4. 10EL SERIES PECL DC CHARACTERISTICS (V<sub>CC</sub>= 5.0 V; V<sub>EE</sub>= 0.0 V (Note 4))

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm.

4. Input and output parameters vary 1:1 with V<sub>CC</sub>. V<sub>EE</sub> can vary +0.25 V / –0.5 V.

5. Outputs are terminated through a 50  $\Omega$  resistor to V<sub>CC</sub> – 2.0 V. 6. V<sub>IHCMR</sub> min varies 1:1 with V<sub>EE</sub>, V<sub>IHCMR</sub> max varies 1:1 with V<sub>CC</sub>. The V<sub>IHCMR</sub> range is referenced to the most positive side of the differential input signal. Normal operation is obtained if the HIGH level falls within the specified range and the peak-to-peak voltage lies between VPP(min) and 1.0 V.

		<b>−40°C</b>				25°C		85°C			
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I <sub>EE</sub>	Power Supply Current		18	22		18	22		18	22	mA
V <sub>OH</sub>	Output HIGH Voltage (Note 2)	-1080	-990	-890	-980	-895	-810	-910	-815	-720	mV
V <sub>OL</sub>	Output LOW Voltage (Note 2)	-1950	-1800	-1650	-1950	-1790	-1630	-1950	-1773	-1595	mV
V <sub>IH</sub>	Input HIGH Voltage (Single-Ended)	-1230		-890	-1130		-810	-1060		-720	mV
V <sub>IL</sub>	Input LOW Voltage (Single-Ended)	-1950		-1500	-1950		-1480	-1950		-1445	mV
VIHCMR	Input HIGH Voltage Common Mode Range (Differential Configuration) (Note 3)	-2.0		-0.4	-2.0		-0.4	-2.0		-0.4	V
I <sub>IH</sub>	Input HIGH Current			150			150			150	μA
IIL	Input LOW Current	0.5			0.5			0.3			μA

Table 5. 10EL SERIES NECL DC CHARACTERISTICS (V<sub>CC</sub>= 0 V; V<sub>EE</sub>= -5.0 V (Note 1))

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm.

Input and output parameters vary 1:1 with V<sub>CC</sub>. V<sub>EE</sub> can vary +0.25 V / -0.5 V.
Outputs are terminated through a 50 Ω resistor to V<sub>CC</sub> - 2.0 V.
V<sub>IHCMR</sub> min varies 1:1 with V<sub>EE</sub>, V<sub>IHCMR</sub> max varies 1:1 with V<sub>CC</sub>. The V<sub>IHCMR</sub> range is referenced to the most positive side of the differential input signal. Normal operation is obtained if the HIGH level falls within the specified range and the peak-to-peak voltage lies between V<sub>PP(min)</sub> and 1.0 V.

# MC10EL05, MC100EL05

		-40°C			25°C			85°C			
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I <sub>EE</sub>	Power Supply Current		18	22		18	22		21	25	mA
V <sub>OH</sub>	Output HIGH Voltage (Note 2)	3915	3995	4120	3975	4045	4120	3975	4050	4120	mV
V <sub>OL</sub>	Output LOW Voltage (Note 2)	3170	3305	3445	3190	3295	3380	3190	3295	3380	mV
VIH	Input HIGH Voltage (Single-Ended)	3835		4120	3835		4120	3835		4120	mV
VIL	Input LOW Voltage (Single-Ended)	3190		3525	3190		3525	3190		3525	mV
VIHCMR	Input HIGH Voltage Common Mode Range (Differential Configuration) (Note 3)	3.0		4.6	3.0		4.6	3.0		4.6	V
I <sub>IH</sub>	Input HIGH Current			150			150			150	μA
Ι <sub>ΙL</sub>	Input LOW Current	0.5			0.5			0.5			μA

### Table 6. 100EL SERIES PECL DC CHARACTERISTICS (V<sub>CC</sub>= 5.0 V; V<sub>EE</sub>= 0.0 V (Note 1))

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm.

1. Input and output parameters vary 1:1 with V<sub>CC</sub>. V<sub>EE</sub> can vary +0.8 V / –0.5 V.

2. Outputs are terminated through a 50  $\Omega$  resistor to V<sub>CC</sub> – 2.0 V. 3. V<sub>IHCMR</sub> min varies 1:1 with V<sub>EE</sub>, V<sub>IHCMR</sub> max varies 1:1 with V<sub>CC</sub>. The V<sub>IHCMR</sub> range is referenced to the most positive side of the differential input signal. Normal operation is obtained if the HIGH level falls within the specified range and the peak-to-peak voltage lies between VPP(min) and 1.0 V.

			–40°C 25°C			85°C					
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I <sub>EE</sub>	Power Supply Current		18	22		18	22		21	25	mA
V <sub>OH</sub>	Output HIGH Voltage (Note 2)	-1085	-1005	-880	-1025	-955	-880	-1025	-955	-880	mV
V <sub>OL</sub>	Output LOW Voltage (Note 2)	-1830	-1695	-1555	-1810	-1705	-1620	-1810	-1705	-1620	mV
V <sub>IH</sub>	Input HIGH Voltage (Single-Ended)	-1165		-880	-1165		-880	-1165		-880	mV
V <sub>IL</sub>	Input LOW Voltage (Single-Ended)	-1810		-1475	-1810		-1475	-1810		-1475	mV
VIHCMR	Input HIGH Voltage Common Mode Range (Differential Configuration) (Note 3)	-2.0		-0.4	-2.0		-0.4	-2.0		-0.4	V
I <sub>IH</sub>	Input HIGH Current			150			150			150	μΑ
IIL	Input LOW Current	0.5			0.5			0.5			μA

Table 7. 100EL SERIES NECL DC CHARACTERISTICS (V<sub>CC</sub>= 0.0 V; V<sub>EE</sub>= -5.0 V (Note 1))

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm.

Input and output parameters vary 1:1 with V<sub>CC</sub>. V<sub>EE</sub> can vary +0.8 V / -0.5 V.
Outputs are terminated through a 50 Ω resistor to V<sub>CC</sub> - 2.0 V.
V<sub>IHCMR</sub> min varies 1:1 with V<sub>EE</sub>, V<sub>IHCMR</sub> max varies 1:1 with V<sub>CC</sub>. The V<sub>IHCMR</sub> range is referenced to the most positive side of the differential input signal. Normal operation is obtained if the HIGH level falls within the specified range and the peak-to-peak voltage lies between V<sub>PP(min)</sub> and 1.0 V.

### MC10EL05, MC100EL05

		-40°C		25°C			85°C				
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
f <sub>max</sub>	Maximum Toggle Frequency		TBD			TBD			TBD		GHz
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay to Output	135	260	440	185	275	390	215	305	420	ps
V <sub>PP</sub>	Input Swing (Note 2)	150		1000	150		1000	150		1000	mV
t <sub>JITTER</sub>	Cycle-to-Cycle Jitter		TBD			TBD			TBD		ps
t <sub>r</sub> t <sub>f</sub>	Output Rise/Fall Times Q (20% – 80%)	100	225	350	100	225	350	100	225	350	ps

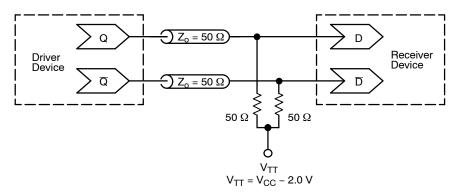
Table 8. AC CHARACTERISTICS (V<sub>CC</sub> = 5.0 V; V<sub>EE</sub> = 0 V or V<sub>CC</sub> = 0 V; V<sub>EE</sub> = -5.0 V (Note 1))

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm.

1. 10 Series: V<sub>EE</sub> can vary +0.25 V / –0.5 V.

100 Series: VEE can vary +0.8 V / -0.5 V.

2. V<sub>PP(min)</sub> is minimum input swing for which AC parameters guaranteed. The device has a DC gain of ≈40.





#### **Resource Reference of Application Notes**

- AN1405/D ECL Clock Distribution Techniques
- AN1406/D Designing with PECL (ECL at +5.0 V)
- AN1503/D ECLinPS™ I/O SPiCE Modeling Kit
- AN1504/D Metastability and the ECLinPS Family
- AN1568/D Interfacing Between LVDS and ECL
- AN1672/D The ECL Translator Guide
- AND8001/D Odd Number Counters Design
- AND8002/D Marking and Date Codes
- AND8020/D Termination of ECL Logic Devices
- AND8066/D Interfacing with ECLinPS
- AND8090/D AC Characteristics of ECL Devices

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\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

### STYLES ON PAGE 2

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#### SOIC-8 NB CASE 751-07 **ISSUE AK**

STYLE 1: PIN 1. EMITTER COLLECTOR 2. COLLECTOR З. 4. EMITTER EMITTER 5. BASE 6. 7 BASE 8. EMITTER STYLE 5: PIN 1. DRAIN 2. DRAIN З. DRAIN DRAIN 4. 5. GATE 6. GATE SOURCE 7. 8. SOURCE STYLE 9: PIN 1. EMITTER, COMMON COLLECTOR, DIE #1 COLLECTOR, DIE #2 2. З. EMITTER, COMMON 4. 5. EMITTER, COMMON 6. BASE, DIE #2 BASE, DIE #1 7. 8. EMITTER, COMMON STYLE 13: PIN 1. N.C. 2. SOURCE 3. SOURCE GATE 4. 5. DRAIN 6. DRAIN DRAIN 7. 8. DRAIN STYLE 17: PIN 1. VCC 2. V2OUT V10UT З. 4. TXE 5. RXE 6. VFF GND 7. 8. ACC STYLE 21: PIN 1. CATHODE 1 2. CATHODE 2 З. CATHODE 3 CATHODE 4 4. 5. CATHODE 5 6. COMMON ANODE COMMON ANODE 7. 8. CATHODE 6 STYLE 25: PIN 1. VIN 2 N/C З. REXT 4. GND 5. IOUT 6. IOUT 7. IOUT 8. IOUT STYLE 29: BASE, DIE #1 PIN 1. EMITTER, #1 BASE, #2 2. З. EMITTER, #2 4. 5 COLLECTOR, #2 COLLECTOR, #2 6.

STYLE 2: PIN 1. COLLECTOR, DIE, #1 2. COLLECTOR, #1 COLLECTOR, #2 З. 4 COLLECTOR, #2 BASE, #2 5. EMITTER, #2 6. 7 BASE #1 EMITTER, #1 8. STYLE 6: PIN 1. SOURCE 2. DRAIN 3. DRAIN SOURCE 4. SOURCE 5. 6. GATE GATE 7. 8. SOURCE STYLE 10: PIN 1. GROUND BIAS 1 OUTPUT 2. З. GROUND 4. 5. GROUND BIAS 2 INPUT 6. 7. 8. GROUND STYLE 14: PIN 1. N-SOURCE 2. N-GATE P-SOURCE 3 P-GATE 4. 5. P-DRAIN 6. P-DRAIN N-DRAIN 7. 8. N-DRAIN STYLE 18: PIN 1. ANODE 2. ANODE SOURCE 3. GATE 4. 5. DRAIN 6 DRAIN CATHODE 7. 8. CATHODE STYLE 22: PIN 1. I/O LINE 1 2. COMMON CATHODE/VCC 3 COMMON CATHODE/VCC I/O LINE 3 4. 5. COMMON ANODE/GND 6. I/O LINE 4 7. I/O LINE 5 8. COMMON ANODE/GND STYLE 26: PIN 1. GND 2 dv/dt ENABLE З. 4. ILIMIT 5. SOURCE SOURCE 6. SOURCE 7. 8. VCC STYLE 30: PIN 1. DRAIN 1 DRAIN 1 2 GATE 2 З. SOURCE 2 4. SOURCE 1/DRAIN 2 SOURCE 1/DRAIN 2 5. 6.

STYLE 3: PIN 1. DRAIN, DIE #1 2. DRAIN, #1 3. DRAIN, #2 4. DRAIN, #2 5. GATE, #2 6. SOURCE, #2 7. GATE, #1 8. SOURCE, #1
STYLE 7: PIN 1. INPUT 2. EXTERNAL BYPASS 3. THIRD STAGE SOURCE 4. GROUND 5. DRAIN 6. GATE 3 7. SECOND STAGE Vd 8. FIRST STAGE Vd
STYLE 11: PIN 1. SOURCE 1 2. GATE 1 3. SOURCE 2 4. GATE 2 5. DRAIN 2 6. DRAIN 2 7. DRAIN 1 8. DRAIN 1
STYLE 15: PIN 1. ANODE 1 2. ANODE 1 3. ANODE 1 4. ANODE 1 5. CATHODE, COMMON 6. CATHODE, COMMON 7. CATHODE, COMMON 8. CATHODE, COMMON
STYLE 19: PIN 1. SOURCE 1 2. GATE 1 3. SOURCE 2 4. GATE 2 5. DRAIN 2 6. MIRROR 2 7. DRAIN 1 8. MIRROR 1
STYLE 23: PIN 1. LINE 1 IN 2. COMMON ANODE/GND 3. COMMON ANODE/GND 4. LINE 2 IN 5. LINE 2 OUT 6. COMMON ANODE/GND 7. COMMON ANODE/GND 8. LINE 1 OUT
STYLE 27: PIN 1. ILIMIT 2. OVLO 3. UVLO 4. INPUT+ 5. SOURCE 6. SOURCE 7. SOURCE 8. DRAIN

#### DATE 16 FEB 2011

STYLE 4: ANODE ANODE PIN 1. 2. ANODE З. 4. ANODE ANODE 5. 6. ANODE 7 ANODE COMMON CATHODE 8. STYLE 8: PIN 1. COLLECTOR, DIE #1 2. BASE, #1 BASE, #2 З. COLLECTOR, #2 4. COLLECTOR, #2 5. 6. EMITTER, #2 EMITTER, #1 7. 8. COLLECTOR, #1 STYLE 12: PIN 1. SOURCE SOURCE SOURCE 2. 3. 4. GATE 5. DRAIN 6. DRAIN DRAIN 7. 8. DRAIN STYLE 16: PIN 1. EMITTER, DIE #1 2. BASE, DIE #1 EMITTER, DIE #2 3 BASE, DIE #2 4. 5. COLLECTOR, DIE #2 6. COLLECTOR, DIE #2 COLLECTOR, DIE #1 7. COLLECTOR, DIE #1 8. STYLE 20: PIN 1. SOURCE (N) GATE (N) SOURCE (P) 2. 3. 4. GATE (P) 5. DRAIN 6. DRAIN DRAIN 7. 8. DRAIN STYLE 24: PIN 1. BASE 2. EMITTER З. COLLECTOR/ANODE COLLECTOR/ANODE 4. 5. CATHODE CATHODE COLLECTOR/ANODE 6. 7. COLLECTOR/ANODE 8. STYLE 28: PIN 1. SW\_TO\_GND 2. DASIC OFF DASIC\_SW\_DET 3. 4. GND 5. 6. V MON VBULK 7. VBULK 8. VIN

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8. GATE 1

7.

8

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COLLECTOR, #1

COLLECTOR, #1